

Very low capacitance bidirectional ESD protection diodeRev. 1 — 7 December 2010Product data

Product data sheet

1. **Product profile**

1.1 General description

Very low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is housed in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- Bidirectional ESD protection of one line Low clamping voltage: V_{CL} = 12.5 V
- Ultra small SMD plastic package
- Solderable side pads
- Package height typ. 0.37 mm
- Very low diode capacitance: C_d = 11 pF IEC 61000-4-5 (surge); I_{PP} = 4.8 A
- Max. peak pulse power: P_{PP} = 45 W

1.3 Applications

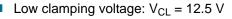
- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber Identity Module (SIM) card protection

1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	11	13	pF



- Ultra low leakage current: I_{RM} < 1 nA</p>
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified
- Communication systems
- Portable electronics
- 10/100 Mbit/s Ethernet
- FireWire



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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode 1	[1]	
2	cathode 2		1-1-2 006aab04:
		Transparent top view	

3. Ordering information

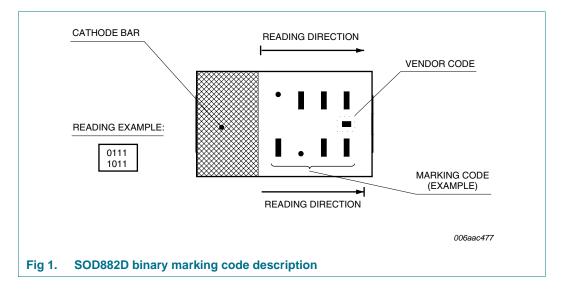
Table 3. Orderin	ng informatio	n	
Type number	Package		
	Name	Description	Version
PESD5V0V1BLD	-	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882D

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
PESD5V0V1BLD	0111 0000

[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
P _{PP}	peak pulse power	t _p = 8/20 μs	<u>[1]</u> _	45	W
I _{PP}	peak pulse current	t _p = 8/20 μs	<u>[1]</u> _	4.8	А
Per device					
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 6.ESD maximum ratings

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1]</u> _	30	kV
		machine model	-	2	kV
		MIL-STD-883 (human body model)	-	16	kV

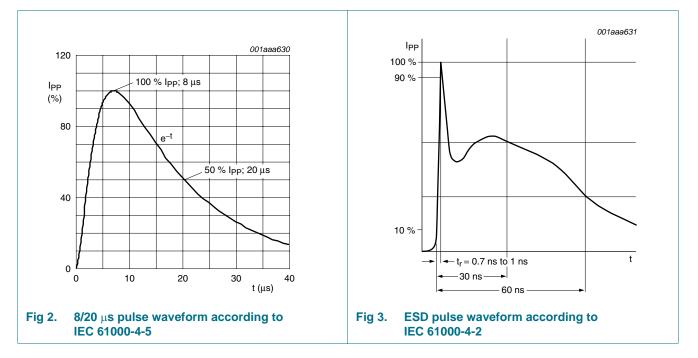
[1] Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV

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6. Characteristics

Table 8.Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

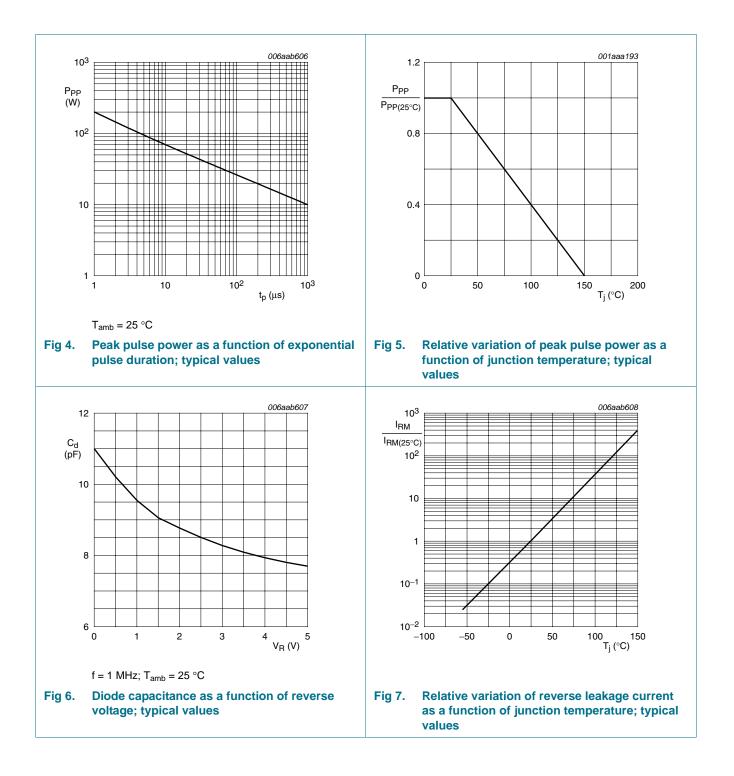
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{RWM}	reverse standoff voltage		-	-	5	V
I _{RM}	reverse leakage current	$V_{RWM} = 5 V$	-	< 1	10	nA
V _{BR}	breakdown voltage	I _R = 5 mA	5.8	6.8	7.8	V
C _d	diode capacitance	f = 1 MHz; V _R = 0 V	-	11	13	pF
V _{CL}	clamping voltage	I _{PP} = 4.8 A	<u>[1]</u> _	-	12.5	V
r _{dyn}	dynamic resistance	I _R = 10 A	[2] _	0.2	-	Ω

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

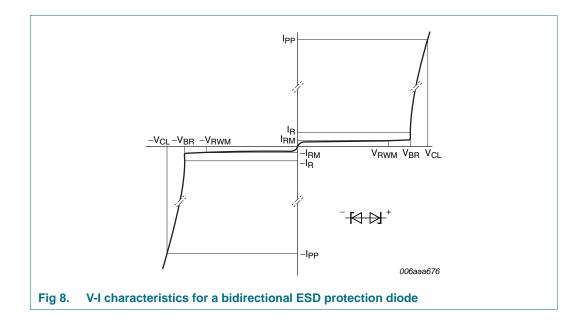
[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5.1-2008.

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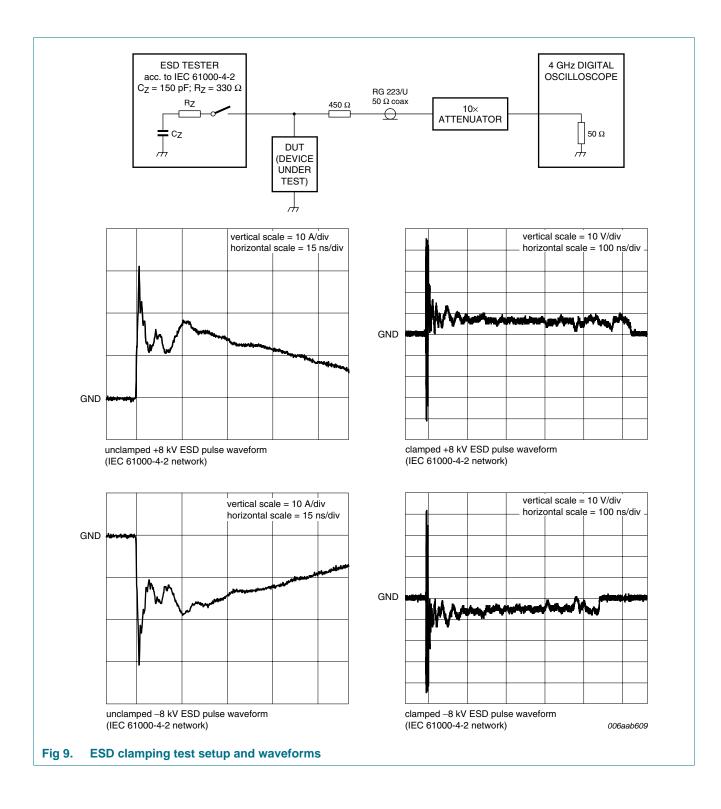
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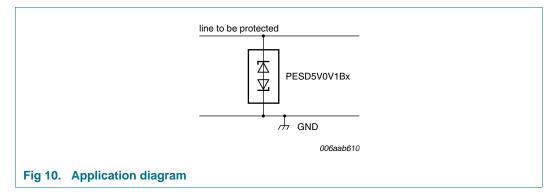


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7. Application information

The PESD5V0V1BLD is designed for the protection of one bidirectional data or signal line from the damage caused by ESD and surge pulses. The device may be used on lines where the signal polarities are both, positive or negative with respect to ground. The PESD5V0V1BLD provides a surge capability of 45 W per line for an 8/20 μ s waveform.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

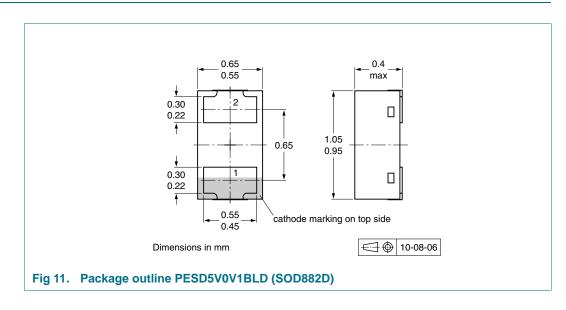
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 9. Packing methods

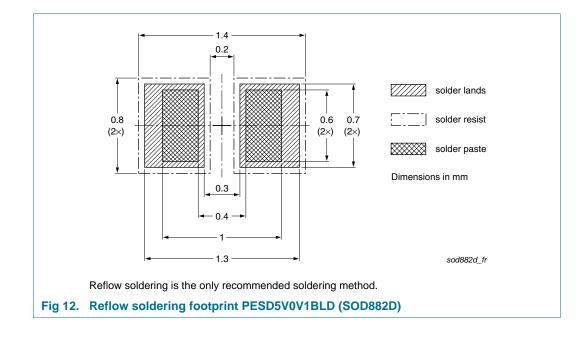
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PESD5V0V1BLD	SOD882D	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 10. Revision hist	a 10. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
PESD5V0V1BLD v.1	20101207	Product data sheet	-	-			

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

PESD5V0V1BLD

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